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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/605,585	10/10/2003	Masaki Takaoka	RHM-US020052	2584
22919 7590 03/26/2007 GLOBAL IP COUNSELORS, LLP 1233 20TH STREET, NW, SUITE 700 WASHINGTON, DC 20036-2680			EXAMINER	
			NADAV, ORI .	
			ART UNIT	PAPER NUMBER
			2811	
SHORTENED STATUTOR	Y PERIOD OF RESPONSE	MAIL DATE	DELIVERY MODE	
3 MO	NTHS	03/26/2007	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

	Application No.	Applicant(s)			
	10/605,585	TAKAOKA ET AL			
Office Action Summary	Examiner	Art Unit			
	Ori Nadav	2811			
<ul> <li>The MAILING DATE of this communication app</li> <li>Period for Reply</li> </ul>	ears on the cover sheet with the c	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).					
Status					
2a) ☐ This action is <b>FINAL</b> . 2b) ☐ This 3) ☐ Since this application is in condition for allowan	,—				
Disposition of Claims					
4) ☐ Claim(s) 1,4 and 13 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration.  5) ☐ Claim(s) is/are allowed.  6) ☐ Claim(s) 1,4 and 13 is/are rejected.  7) ☐ Claim(s) is/are objected to.  8) ☐ Claim(s) are subject to restriction and/or election requirement.					
Application Papers	•				
9) The specification is objected to by the Examiner 10) The drawing(s) filed on is/are: a) access applicant may not request that any objection to the conference of the	epted or b) objected to by the E drawing(s) be held in abeyance. See on is required if the drawing(s) is obj	37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
<ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>					
Attachment(s)					
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 11/9/06.	4) Interview Summary ( Paper No(s)/Mail Da 5) Notice of Informal Pa 6) Other:	te			

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### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

. Claims 1 and 13 are rejected under 35 U.S.C. 102(b) as being anticipated by Ishibashi (5,202,281).

Ishibashi teaches in figures 3 or 4 and related text a semiconductor device, comprising:

a unitary and non-layered semiconductor substrate 4 comprising a thin portion that is thinner than adjacent portions of the semiconductor substrate, and a recessed portion formed below the thin portions;

wherein the etching rate of the thin portion is slower than that of the surrounding portions of the semiconductor substrate (since a dopant 3 is infused in the thin portion that is immediately adjacent in the at least one through hole),

at least one through hole is formed in the thin portion that extends from the recessed portion, and entirely through the thin portion to the upper surface of the semiconductor substrate 4.

Regarding claim 13, Ishibashi teaches that semiconductor substrate 4 has a specific resistance (column 3, lines 20-21). This means that the substrate must be doped.

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Therefore, by considering the "dopant" as the dopant with which the entire substrate is doped, then Ishibashi teaches a dopant is infused in the entire thin portion, as claimed.

## Claim Rejections - 35 USC § 102/3

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 4 is rejected under 35 U.S.C. 102(b) as anticipated by or, in the alternative, under 35 U.S.C. 103(a) as obvious over Ishibashi

Ishibashi teaches in figures 3 or 4 and related text substantially the entire claimed structure, as applied to claim 1 above, except a thin portion is formed by means of a selective oxide film.

The claimed limitations of a thin portion being formed by means of a selective oxide film are process limitations which would not carry patentable weight in this claim drawn to a structure, because distinct structure is not necessarily produced.

Note that a "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17 (footnote 3). See also In re Brown, 173 USPQ 685; In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324; In re Avery, 186 USPQ 161; In re Wertheim, 191 USPQ 90 (209 USPQ 554 does not deal with this issue); and In re Marosi et al., 218 USPQ 289, all of which make it clear that it is the

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patentability of the final product per se which must be determined in a "product by process" claim, and not the patentability of the process, and that an old or obvious product produced by a new method is not patentable as a product, whether claimed in "product by process" claims or not. Note that the applicant has the burden of proof in such cases, as the above case law makes clear.

#### Response to Arguments

Applicant is baffled by the examiner's assertion that "Positioning an element "immediately adjacent" or "far" from another element is a relative location, which would not specify the exact location of the first element with respect to the second element", and argues that there is no statute or case law that requires a claim to recite the location of first element with respect to the second element with the degree of precision seemingly required by the Examiner.

The examiner agrees that applicant is not required to recite the exact location of a first element with respect to a second element. However, the examiner's assertion that "Positioning an element "immediately adjacent" or "far" from another element is a relative location, which would not specify the exact location of the first element with respect to the second element", provides the basis for using Ishibashi as anticipating the claimed invention.

Applicant argues that the "Examiner's overly broad interpretation of the term "immediately adjacent" renders this term essentially meaningless", because the dopant

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is infused in a portion of the thin portion that is on the opposite side of the thin portion from the through hole.

Positioning an element "immediately adjacent" or "far" from another element is a relative location and it does not specify the exact location of the first element with respect to the second element. That is, a first element being e.g. 1nm away from the second element, can be described as "immediately adjacent" or "far" from each other, depending on the reference point. Applicant agrees that the phrase "immediately adjacent" does not describe the location of first element with respect to the second element with degree of precision. Thus, due to lack of an exact location of the first element with respect to the second element, the Ishibashi reference anticipates the claimed invention.

#### Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

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the advisory action. In no event, however, will the statutory period for reply expire later

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than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Ori Nadav whose telephone number is 571-272-1660.

The examiner can normally be reached between the hours of 7 AM to 4 PM (Eastern

Standard Time) Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Richard Elms can be reached on 571-272-1869. The fax phone number for

the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the

Patent Application Information Retrieval (PAIR) system. Status information for

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O.N. 3/20/07 ORI NADAV
PRIMARY EXAMINER
TECHNOLOGY CENTER 2800

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